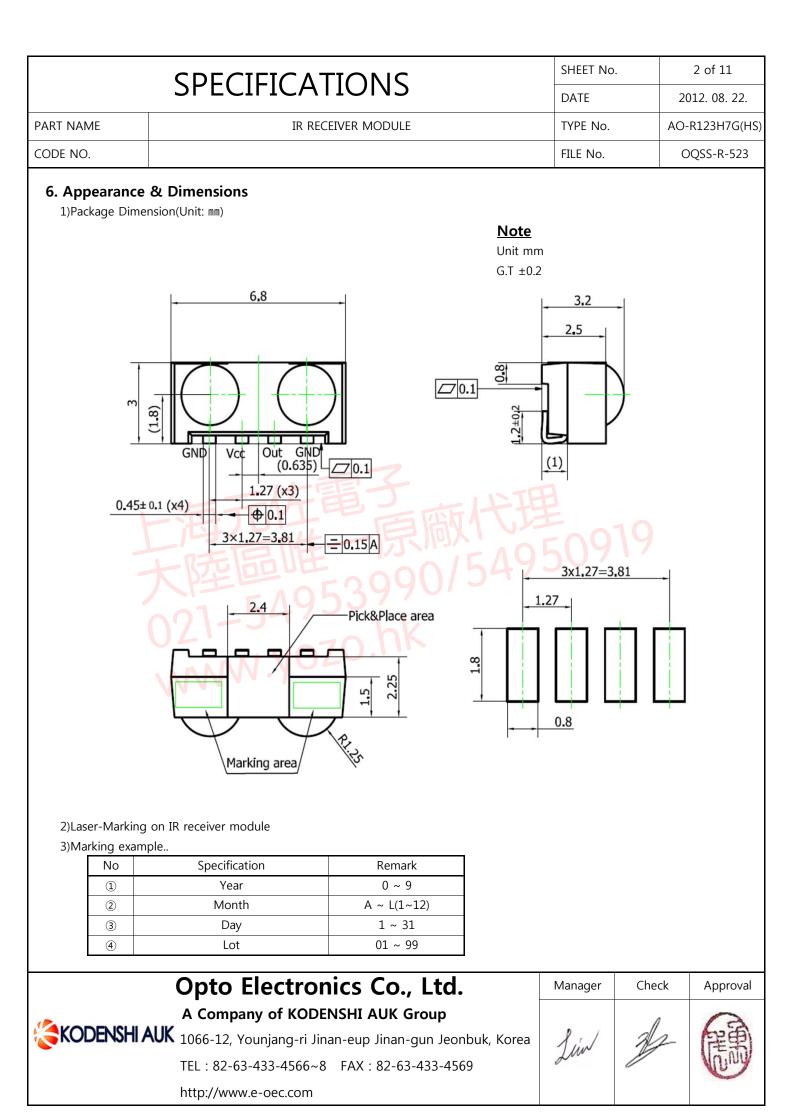
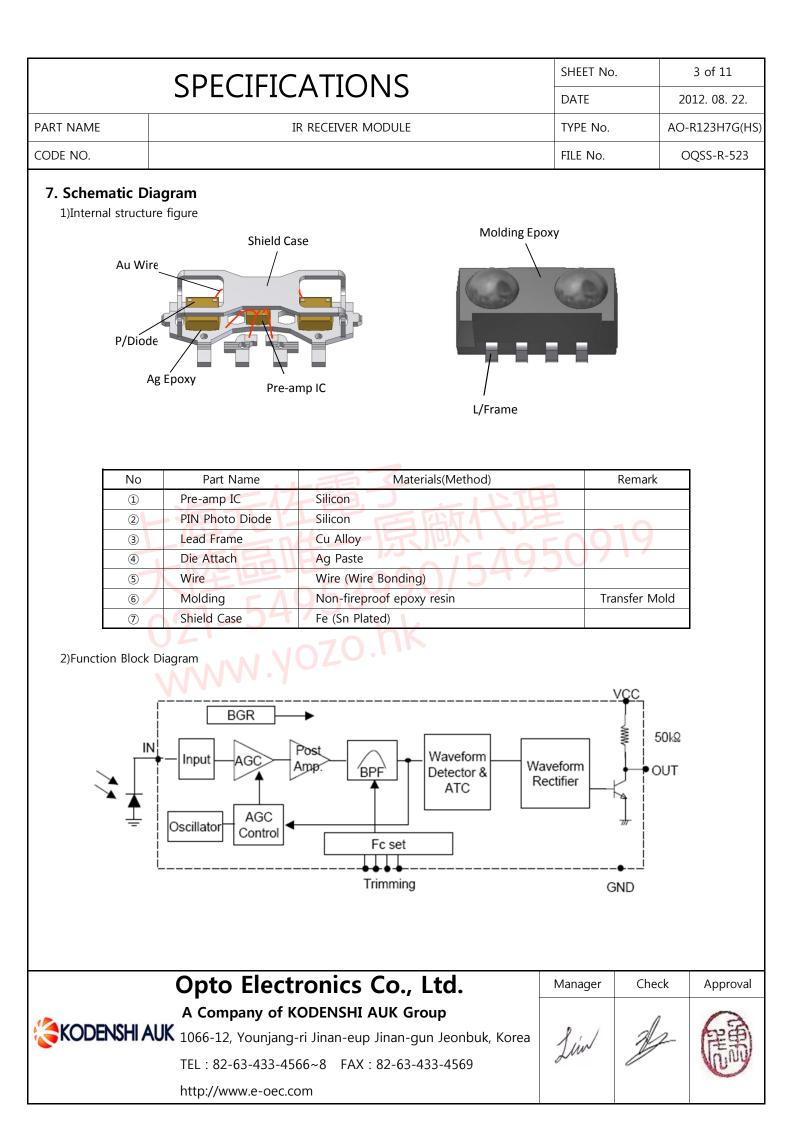
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| PART NAME   | IR RECEIVER MODULE   | TYPE No.                            | AO    | -R123H7G(HS) |
| CODE NO.  |  | FILE No.                            | C     | DQSS-R-523   |
| <b>1. Application</b><br>This Specificati   | on is applied to inspection and approval of the IR Receiver Module for TV  | , DVD, STB et                       | с     |              |
| The PIN Photo<br>The module ha  | niniaturized receiver for infrared remote control system.<br>diode and preamplifier are assembled on lead frame. The epoxy pacakge i<br>as excellent performance even in disturbed ambient light application and p<br>crolled output pulses.   | 0                                   |       |              |
| <ul> <li>3)Low current of 4)Band pass file</li> <li>5)Epoxy IR filter</li> <li>6)Maximum internal filter</li> <li>7)Internal filter</li> <li>8)Internal pullet</li> <li>4. Absolute N</li> <li>1)Supply voltage</li> <li>2)Supply current</li> <li>3)Output current</li> <li>4)Operating ternal</li> <li>5)Storage tempe</li> <li>6)Reflow solder</li> <li>5. Cautions</li> <li>1)Store and us</li> <li>2)Store and us</li> <li>3)In order to persoldering iront</li> <li>4)The ripple not</li> <li>Thus, in order</li> <li>5)When a disture</li> </ul> | ing supply voltage : 2.7V ~ 6.0V<br>consumption : 3.0V(0.4mA), 5.0V(0.5mA)<br>ter center frequency : 37.9KHz<br>er characteristic : 940nm<br>terference safety against optical and electrical disturbance<br>for a high frequency lighting fluorescent lamp<br>up output : 50kΩ<br><b>Iaximum Ratings</b><br>ge : 0 ~ 7.0V<br>mt : 0 ~ 3.0mA | <sup>r</sup> module.<br>between Vcc |       |              |
| (b)Continu  | nt(Ex. From tungsten lamp or sunlight)<br>uous signal at center frequency or any other frequency<br>from fluorescent lamps with electronic ballact with high or law modulatio  | n                                   |       |              |
| ©Signals  | from fluorescent lamps with electronic ballast with high or low modulatio  |                                     | 1     |              |
|   | Opto Electronics Co., Ltd.   | Manager                             | Check | Approval     |
| KODENSHI  | A Company of KODENSHI AUK Group<br>AUK 1066-12, Younjang-ri Jinan-eup Jinan-gun Jeonbuk, Korea<br>TEL : 82-63-433-4566~8 FAX : 82-63-433-4569<br>http://www.e-oec.com  | Lin                                 | 3/2-  | 調            |





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|   | SPECIFICATIONS  | DATE   |   | 2012. 08. 22. |
| PART NAME   | IR RECEIVER MODULE  | TYPE No.   | AC  | D-R123H7G(HS) |
| CODE NO.  |   | FILE No.   |   | OQSS-R-523    |
| The function of<br>Photo current<br>IC called "Input<br>The DC part is<br>followed by a<br>The final evalue<br>The "Automat<br>the influences<br>optical burst of<br>The detail of "<br>(1)Input Block<br>(2)AGC-Amplif<br>The detail of "<br>(3)Post-Amplif<br>The most go<br>(4)Band Pass F<br>It is designe<br>on current of<br>(5)AGC Contro<br>It reacts to t<br>The AGC set<br>The AGC do<br>The AGC dis<br>length and of<br>(6)Waveform F<br>Compare wir<br>burst signal,<br>signal size. T<br>(7)Waveform F<br>The integrat<br>It needs sev<br>output is trig | ption of Function Block Diagram<br>of the IC is described with above function block diagram.<br>generated by infrared radiation burst signal equivalently goes through th<br>ut Block".<br>s separated in the coupling cap of the each amplifier and AC signal pass in<br>n automatic gain control amplifier, a post amplifier and a band pass filter<br>uation is done by a waveform detector & ATC, waveform rectifier stage.<br>ic Gain Control" is responsible for the dynamic control if stable working p<br>of disturbing sources. The digital output signal, which is an envelope sig<br>without the carrier frequency, has active low polarity.<br>the each block is as below.<br>reacts to the photo diode as a frequency-dependent load resistance.<br>fier generates most of the voltage gain of the whole circuitry where by th<br>ier generates a signal gain to be fit to band pass filter input by limiting s<br>to the voltage gain is decided by a load resistance and emitter resistance.<br>filter is an important part of the circuit to get a good performance in dist<br>d to achieve a specified frequency response and exhibit different character<br>alue of each element. | to a pre-ample<br>point to supprimal of the incomposition<br>ignal amplification<br>ignal amplification<br>urbed ambient<br>eristics dependent<br>ambient light<br>t pulse.<br>arks are burst<br>utput and detent<br>filter output<br>putput signals.<br>oltage.<br>aded and the | ifier<br>ess<br>oming<br>n.<br>de.<br><b>19</b><br>ding |               |
|   | Opto Electronics Co., Ltd.  | Manager  | Check   | Approval      |
| <b>KODENSHI</b>   | A Company of KODENSHI AUK Group<br>AUK 1066-12, Younjang-ri Jinan-eup Jinan-gun Jeonbuk, Korea<br>TEL : 82-63-433-4566~8 FAX : 82-63-433-4569<br>http://www.e-oec.com   | Lim  | de la   | E             |

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| PART NAME      | IR RECEIVER MODULE | TYPE No.      | AO-R123H7G(HS) |
| CODE NO.       |                    | FILE No.      | OQSS-R-523     |

### 8. Electro-Optical Characteristics (At 25°C unless otherwise notes)

## 1)Absolute Maximum Ratings

| Parameter                        | Symbol | Rating                       | Unit |
|----------------------------------|--------|------------------------------|------|
| Supply Voltage                   | Vcc    | 0 ~ 6.0                      | V    |
| Output Current                   | lout   | 0 ~ 2.5                      | mA   |
| Operating Temperature            | Topr   | -20 ~ +80                    | °C   |
| Storage Temperature              | Tstg   | -30 ~ +85                    | °C   |
| Soldering Temperature(*1)        | Tsol   | 260, t<5sec                  | °C   |
| Reflow Soldering Temperature(*1) | Tsol   | 260, t<10sec                 | °C   |
| Moisture Sensitive Level(*2)     |        | Level 5a (≤30°C/60%RH 24Hour | s)   |

#### (\*1)Pb Free Solder

(\*2)JEDEC Standard J-STD-020C

#### 2)Recommended operating Conditions

| Parameter         | Symbol | Rating    | Unit |
|-------------------|--------|-----------|------|
| Operating Voltage | Vcc    | 2.7 ~ 6.0 | V    |
| Input Frequency   | fin    | 36 ~ 40   | kHz  |

# 3)Elector\_Optical Characteristics [Vcc=5.0V, Vcc=3.0V]

| Parameter                          | Symbol          | Condition               | Min        | Тур  | Max | Unit |
|------------------------------------|-----------------|-------------------------|------------|------|-----|------|
| Supply Voltage                     | Vcc             |                         | 2.7        |      | 5.5 | V    |
| Supply Current                     |                 | No Input Vcc=5V         | 0.2        | 0.5  | 0.7 | mA   |
| supply current 54                  | Icc             | Signal Vcc=3V           |            | 0.45 |     | IIIA |
| Peak Wavelength (%1)               | λр              | hk                      | -          | 940  | -   | nm   |
| B.P.F Center Frequency (%2)        | fo              |                         | -          | 37.9 | -   | kHz  |
| High Level Output Voltage (※1)     | V <sub>OH</sub> | 30cm over the ray axis  | 4.5        | 5.0  | -   | V    |
| Low Level Output Voltage (%1)      | V <sub>OL</sub> | Soull over the ray axis | -          | 0.2  | 0.4 | V    |
| High Level Output Pulse Width (※1) | t <sub>WH</sub> | Burst Wave = $600\mu$ s | 400        | -    | 800 | μs   |
| Low Level Output Pulse Width (X1)  | t <sub>WL</sub> | Period = $1.2$ ms       | 400        | -    | 800 | μs   |
| Arrival Dictorso (X1)              | D               | ±0°                     | 20         | -    | -   | m    |
| Arrival Distance (※1)              | D               | ±30°                    | 15         | -    | -   | m    |
| Output Form                        |                 | Active                  | Low Output | t    |     |      |

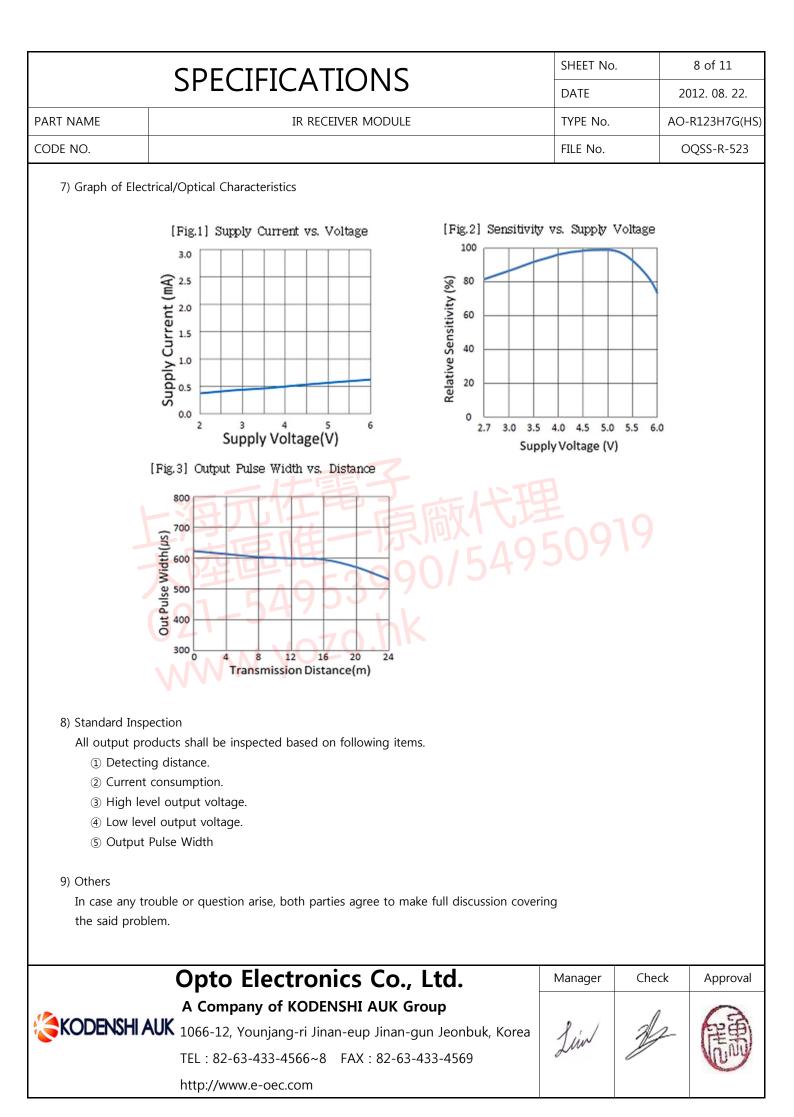
× 1. 600/600μs burst wave is transmitted by standard(Fig.2, Fig.3) transmitter. However, it measured after the initial transmission pulse is 10(60ms) pulse.

% 2. The following band pass frequencies are available.(36.7kHz/37.9kHz/40kHz) Carrier frequencies adjusted by zener-diode fusing method.



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| PART NAME  | IR RECEIVER MODULE   | TYPE No.       | AO-      | R123H7G(HS)  |
| CODE NO.   |  | FILE No.       | С        | QSS-R-523    |
| <ul> <li>4) Measurement</li> <li>① Fig.1 Burst</li> <li>※ LCD Dimming have</li> <li>1) Data word length =</li> <li>2) tpause = Min. 59ms</li> <li>3) Duty(Σtburst /T) = 1</li> </ul> | wave, Output wave<br>$ \begin{array}{c} \hline Transmitting time for 1 block:T \\ \hline Data word \\ \hline tpause \\ $ |                |          |              |
| When sta   | Standard transmitter   | become Io=5uA  | 9<br>p-p |              |
|  | e measurement condition Fig.2. (The radiant intensity of standard transmit   | ter : 50mW/sr) |          |              |
| HP-5FR4  | : standard photodiode has short current Isc=32uA at E=1000(lx)   |                |          |              |
| ③ Fig.3 Test   | Condition of Arrival Distance  |                |          |              |
|  | Receiver<br>AO-R123C6H-HS(T)<br>Standard transmitter<br>Effective distance: L  |                |          |              |
|  | ( $\Theta$ : Indicates horizontal and Vertical<br>t light source : Detecting surface's illumination shall be 100Lux under ordi   | nary white     |          |              |
|  | Opto Electronics Co., Ltd.   | Manager        | Check    | Approval     |
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| CODE NO.  |   | FILE No.  |             | OQSS-R-523    |
| However th<br>Some exan<br>a. Signal<br>b. Conti  | uppression<br>turbance signal is applied to the AO-R123H7G(HS)., Series, It can receive<br>the sensitivity is reduced to that level that no unexpected pulses will occu<br>aples for such disturbance signals which are suppressed by the AO-R123<br>s from fluorescent lamps with electronic ballast (please refer to Fig.1)<br>nuous signal at 37.9kHz or at any other frequency<br>ht (from tungsten lamp or sunlight)   | r.  |             |               |
| There will b<br>according t   | t Lamp with Modulation]<br>The signals shown in [Fig. 1] come from a fluore<br>electronic ballast Which is operated at 60 Hz and<br>A different kind of disturbance signal is caused by<br>lamps with electronic ballast.<br>Typically the oscillating frequency of the optical d<br>signal of such lamps is in the range between 20kH<br>This frequency is twice of the electrical oscillating<br>of the driver circuit in the lamp ballast.<br>All AO-R123H7G(HS). Series IR receiver modules of<br>disturbance signals efficiently<br>be unexpected output pulses due to such lamps. However, sensitivity will<br>o the strength of the disturbance signal. More critical are the electronic<br>of the oscillating amplitude are more critical | 120Hz power lin<br>fluorescent<br>isturbance<br>Iz and 50kHz.<br>frequency<br>an suppress suc<br>be reduced   | ine frequer | ncy.          |
| peripheral p<br>Using the fi<br>resistor, cor<br>2 The ripple<br>Thus, in orc<br>Vcc and GN<br>3 Store and<br>4 Store and<br>5 In order to<br>iron are cor<br>6 In order to<br>shall be gro<br>7 Please use | use where there is no force causing transformation or change in quality.<br>use where there is no extreme humidity.<br>prevent damage from static electricity, make sure that the human body<br>nected to ground before using.<br>prevent electrostatic discharge of integrated circuit, human body and so  | e receiver modu<br>ponents such as<br>ver module.<br>$7\mu$ F) between<br>and the solder<br>oldering iron, et | ring        |               |
| <b>EXCODENSHI</b> A   | Opto Electronics Co., Ltd.<br>A Company of KODENSHI AUK Group<br>UK 1066-12, Younjang-ri Jinan-eup Jinan-gun Jeonbuk, Korea<br>TEL : 82-63-433-4566~8 FAX : 82-63-433-4569<br>http://www.e-oec.com  | Manager<br>Juin   | Check       | Approval      |



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| CODE NO.       |                    | FILE No.      | OQSS-R-523     |

## 9. Reliability Test Item and Standard.

- 1) All output products shall satisfy below Reliability test items.
- 2) Related sampling quantity and acceptance/failure judgment standard accordance with MIL standard MIL-STD-833 is as listed below.

| ①Confidence Level: 90% |
|------------------------|
| 2LPTD: 10% / 20%       |

| Test Item                  | Test Conditions   | Judgment Standard   | Fail@<br>Sample(n)   |
|----------------------------|---|---|--|
| High Temp. Storage (※ 2)   | Ta=+120°C, t=500HR's  | VOH(Vcc=5V)   | C=0/n=22   |
| Low Temp. Storage (※ 2)    | Ta=-30°C, t=500HR's   | High level output voltage   | C=0/n=22   |
| High Temp. Bias (※ 1, ※ 2) | Ta=+85°C, t=500HR's   | Low level output voltage  | C=0/n=22   |
| High Temp./High Hum.(※ 2)  | Ta=+85°C, 90%RH, t=500HR's  | VOL<0.4V<br>Icc(Vcc=5.0V)   | C=0/n=22   |
| Temperature Cycle(X 2)     | Ta=-20°C(0.5HR) to +85°C(0.5HR) 20 Cycle  | Consumption Current<br>Icc<1.5mA<br>D(Vcc=5.0V)<br>Arrival Distance: D>8m   | C=0/n=22   |
| P.C.T(% 2)                 | Ta=+121°C, 100%RH, P=2atm, t=4HR's  |   | C=0/n=22   |
| Solder Heat(% 2, % 5)      | Ta=260±5°C, t=5s  |   | C=0/n=11   |
| Solder ability(% 5)        | Solder Temp.: 260±5°C, t=5s<br>Pb Free Solder: Sn/Cu  | Leads shall be covered<br>By solder more than 95%   | C=0/n=11   |
|                            | High Temp. Storage (% 2)<br>Low Temp. Storage (% 2)<br>High Temp. Bias (% 1, % 2)<br>High Temp./High Hum.(% 2)<br>Temperature Cycle(% 2)<br>P.C.T(% 2)<br>Solder Heat(% 2, % 5) | High Temp. Storage ( $\xee$ 2)Ta=+120°C, t=500HR'sLow Temp. Storage ( $\xee$ 2)Ta=-30°C, t=500HR'sHigh Temp. Bias ( $\xee$ 1, $\xee$ 2)Ta=+85°C, t=500HR'sHigh Temp./High Hum.( $\xee$ 2)Ta=+85°C, 90%RH, t=500HR'sTemperature Cycle( $\xee$ 2)Ta=+20°C(0.5HR) to +85°C(0.5HR) 20 CycleP.C.T( $\xee$ 2)Ta=+121°C, 100%RH, P=2atm, t=4HR'sSolder Heat( $\xee$ 2, $\xee$ 5)Ta=260±5°C, t=5sSolder ability( $\xee$ 5)Solder Temp.: 260±5°C, t=5s | High Temp. Storage (% 2)Ta=+120°C, t=500HR'sVOH(Vcc=5V)Low Temp. Storage (% 2)Ta=-30°C, t=500HR'sVOH->4.5VHigh Temp. Bias (% 1, % 2)Ta=+85°C, t=500HR'sLow level output voltage<br>VOH>4.5VHigh Temp./High Hum.(% 2)Ta=+85°C, 90%RH, t=500HR'sLow level output voltage<br>VOL<0.4V |

%1. Supply voltage of load test is 5V.(Standard Jig of OEC)

\*2. Electro-optical characteristics shall be satisfied after leaving 2 hours in the normal condition.

- \*3. Temperature cycle test shall repeat above condition 20 times under no load.
- %4. The test devices shall be dropped three time on the hard wooden board from a height of 75cm.
- %5. For 5sec (after mounting on PCB with thickness of 1.6mm)

In case any trouble or question arises related to above test items, both parties agree to make full discussion and covering the said matters.



